

Electrical Characteristics^[1] (continued)

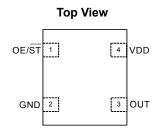
| Parameter and Conditions | Symbol | Min. | Тур. | Max. | Unit | Condition |
|---------------------------|----------|------|--------|------------|-----------|--|
| | | | Startu | p and Resu | me Timing | |
| Startup Time | T_start | - | - | 5 | ms | Measured from the time Vdd reaches its rated minimum value |
| Enable/Disable Time | T_oe | - | - | 130 | ns | f = 110 MHz. For other frequencies, T_oe = 100 ns + 3 * cycles |
| Resume Time | T_resume | - | - | 5 | ms | Measured from the time ST pin crosses 50% threshold |
| Startup Time | T_start | - | - | 5 | ms | Measured from the time Vdd reaches its rated minimum value |
| | | | | Jitter | | |
| RMS Period Jitter | T_jitt | - | 1.76 | 3 | ps | f = 75 MHz, Vdd = 2.5V, 2.8V, 3.0V or 3.3V |
| | | - | 1.78 | 3 | ps | f = 75 MHz, Vdd = 1.8V |
| RMS Phase Jitter (random) | T_phj | - | 0.5 | 0.9 | ps | f = 75 MHz, Integration bandwidth = 900 kHz to 7.5 MHz |
| | | - | 1.3 | 2 | ps | f = 75 MHz, Integration bandwidth = 12 kHz to 20 MHz |

Notes:

1. All electrical specifications in the above table are specified with 15 pF output load and for all Vdd(s) unless otherwise stated.

Pin Description

| Pin | Symbol | | Functionality | | | |
|-----|-----------|------------------|--|--|--|--|
| 4 | OE/ ST | Output Enable | H or Open ^[2] : specified frequency output L: output is high impedance. Only output driver is disabled. | | | |
| | 1 Standby | | H or Open ^[2] : specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to I_std. | | | |
| 2 | GND | Power | Electrical ground ^[3] | | | |
| 3 | OUT | Output | Oscillator output | | | |
| 4 | VDD | Power | Power supply voltage ^[3] | | | |



Notes:

2. A pull-up resistor of <10 k Ω between OE/ \overline{ST} pin and Vdd is recommended in high noise environment. 3. A capacitor value of 0.1 μ F between Vdd and GND is required.

Absolute Maximum

Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

| Parameter | Min. | Max. | Unit |
|--|------|------|------|
| Storage Temperature | -65 | 150 | °C |
| VDD | -0.5 | 4 | V |
| Electrostatic Discharge | - | 2000 | V |
| Soldering Temperature (follow standard Pb free soldering guidelines) | - | 260 | °C |
| Junction Temperature | - | 150 | °C |

Thermal Consideration

| Package | θJA, 4 Layer Board (°C/W) | θJA, 2 Layer Board (°C/W) | θJC, Bottom (°C/W) |
|---------|------------------------------|------------------------------|-----------------------|
| 7050 | 191 | 263 | 30 |
| 5032 | 97 | 199 | 24 |
| 3225 | 109 | 212 | 27 |
| 2520 | 117 | 222 | 26 |
| 2016 | 124 | 227 | 26 |

Environmental Compliance

| Parameter | Condition/Test Method | | |
|----------------------------|---------------------------|--|--|
| Mechanical Shock | MIL-STD-883F, Method 2002 | | |
| Mechanical Vibration | MIL-STD-883F, Method 2007 | | |
| Temperature Cycle | JESD22, Method A104 | | |
| Solderability | MIL-STD-883F, Method 2003 | | |
| Moisture Sensitivity Level | MSL1 @ 260°C | | |



Test Circuit and Waveform^[4]

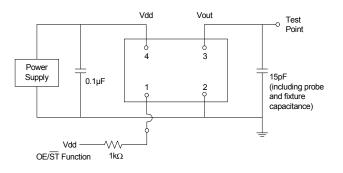
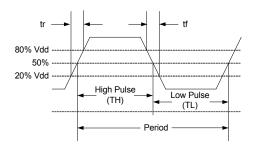
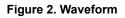


Figure 1. Test Circuit

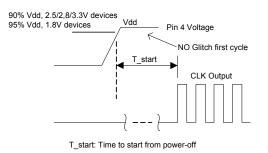




Note:

4. Duty Cycle is computed as Duty Cycle = TH/Period.

Timing Diagram





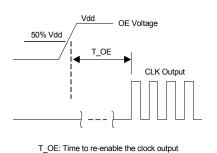
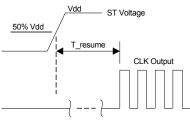


Figure 5. OE Enable Timing (OE Mode Only)

Notes:

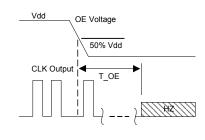
5. SiT1602 supports "no runt" pulses and "no glitch" output during startup or resume.

6. SiT1602 supports gated output which is accurate within rated frequency stability from the first cycle.



T_resume: Time to resume from ST

Figure 4. Standby Resume Timing (ST Mode Only)



T_OE: Time to put the output drive in High Z mode

Figure 5. OE Disable Timing (OE Mode Only)

Rev. 1.2



Performance Plots

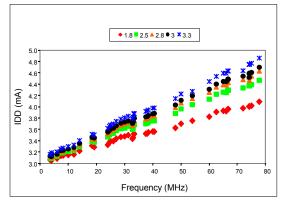
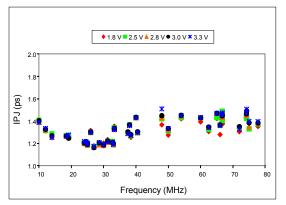
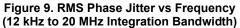
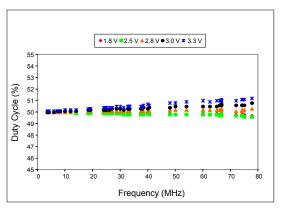


Figure 7. IDD vs Frequency









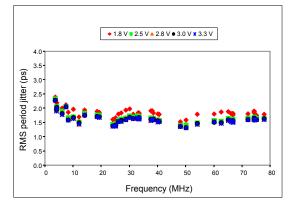


Figure 8. RMS Period Jitter vs Frequency

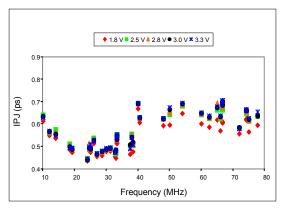


Figure 10. RMS Phase Jitter vs Frequency (900 kHz to 20 MHz Integration Bandwidth)

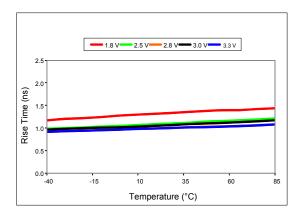


Figure 12. Rise Time vs Temperature, 20 MHz Output

Note:

7. All plots are measured with 15 pF load at room temperature, unless otherwise stated.



Programmable Drive Strength

The SiT1602 includes a programmable drive strength feature to provide a simple, flexible tool to optimize the clock rise/fall time for specific applications. Benefits from the programmable drive strength feature are:

- Improves system radiated electromagnetic interference (EMI) by slowing down the clock rise/fall time
- Improves the downstream clock receiver's (RX) jitter by decreasing (speeding up) the clock rise/fall time.
- Ability to drive large capacitive loads while maintaining full swing with sharp edge rates.

For more detailed information about rise/fall time control and drive strength selection, see the SiTime Applications Note section; <u>http://www.sitime.com/support/application-notes.</u>

EMI Reduction by Slowing Rise/Fall Time

Figure 13 shows the harmonic power reduction as the rise/fall times are increased (slowed down). The rise/fall times are expressed as a ratio of the clock period. For the ratio of 0.05, the signal is very close to a square wave. For the ratio of 0.45, the rise/fall times are very close to near-triangular waveform. These results, for example, show that the 11th clock harmonic can be reduced by 35 dB if the rise/fall edge is increased from 5% of the period to 45% of the period.

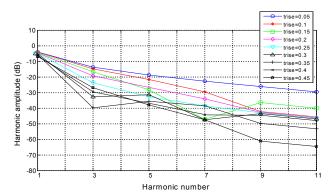


Figure 13. Harmonic EMI reduction as a Function of Slower Rise/Fall Time

Jitter Reduction with Faster Rise/Fall Time

Power supply noise can be a source of jitter for the downstream chipset. One way to reduce this jitter is to increase rise/fall time (edge rate) of the input clock. Some chipsets would require faster rise/fall time in order to reduce their sensitivity to this type of jitter. The SiT1602 provides up to 3 additional high drive strength settings for very fast rise/fall time. Refer to the Rise/Fall Time Tables to determine the proper drive strength.

High Output Load Capability

The rise/fall time of the input clock varies as a function of the actual capacitive load the clock drives. At any given drive strength, the rise/fall time becomes slower as the output load increases. As an example, for a 3.3V SiT1602 device with default drive strength setting, the typical rise/fall time is 1ns for 15 pF output load. The typical rise/fall time slows down to 2.6ns when the output load increases to 45 pF. One can

choose to speed up the rise/fall time to 1.68ns by then increasing the drive strength setting on the SiT1602.

The SiT1602 can support up to 60 pF or higher in maximum capacitive loads with up to 3 additional drive strength settings. Refer to the Rise/Tall Time Tables to determine the proper drive strength for the desired combination of output load vs. rise/fall time

SiT1602 Drive Strength Selection

Tables 1 through 5 define the rise/fall time for a given capacitive load and supply voltage.

- 1. Select the table that matches the SiT1602 nominal supply voltage (1.8V, 2.5V, 2.8V, 3.0V, 3.3V).
- 2. Select the capacitive load column that matches the application requirement (5 pF to 60 pF)
- 3. Under the capacitive load column, select the desired rise/fall times.
- 4. The left-most column represents the part number code for the corresponding drive strength.
- 5. Add the drive strength code to the part number for ordering purposes.

Calculating Maximum Frequency

Based on the rise and fall time data given in Tables 1 through 4, the maximum frequency the oscillator can operate with guaranteed full swing of the output voltage over temperature as follows:

Max Frequency =
$$\frac{1}{5 \times Trf_{20/80}}$$

Where Trf_20/80 is the typical rise/fall time at 20% to 80% Vdd

Example 1

Calculate f_{MAX} for the following condition:

- Vdd = 1.8V (Table 1)
- · Capacitive Load: 30 pF
- Desired Tr/f time = 3 ns (rise/fall time part number code = E)

Part number for the above example: SiT1602AI**E**12-18E-66.666660

Drive strength code is inserted here. Default setting is "-"

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Rise/Fall Time (20% to 80%) vs $\rm C_{\rm LOAD}$ Tables

| | Rise/Fall Time Typ (ns) | | | | | | | | | |
|------------------------------------|-------------------------|-------|-------|-------|-------|--|--|--|--|--|
| Drive Strength \ C _{LOAD} | 5 pF | 15 pF | 30 pF | 45 pF | 60 pF | | | | | |
| L | 6.16 | 11.61 | 22.00 | 31.27 | 39.91 | | | | | |
| Α | 3.19 | 6.35 | 11.00 | 16.01 | 21.52 | | | | | |
| R | 2.11 | 4.31 | 7.65 | 10.77 | 14.47 | | | | | |
| В | 1.65 | 3.23 | 5.79 | 8.18 | 11.08 | | | | | |
| Т | 0.93 | 1.91 | 3.32 | 4.66 | 6.48 | | | | | |
| E | 0.78 | 1.66 | 2.94 | 4.09 | 5.74 | | | | | |
| U | 0.70 | 1.48 | 2.64 | 3.68 | 5.09 | | | | | |
| F or "-": default | 0.65 | 1.30 | 2.40 | 3.35 | 4.56 | | | | | |

| Rise/Fall Time Typ (ns) | | | | | | | | |
|------------------------------------|------|-------|-------|-------|-------|--|--|--|
| Drive Strength $\ C_{\text{LOAD}}$ | 5 pF | 15 pF | 30 pF | 45 pF | 60 pF | | | |
| L | 4.13 | 8.25 | 12.82 | 21.45 | 27.79 | | | |
| Α | 2.11 | 4.27 | 7.64 | 11.20 | 14.49 | | | |
| R | 1.45 | 2.81 | 5.16 | 7.65 | 9.88 | | | |
| В | 1.09 | 2.20 | 3.88 | 5.86 | 7.57 | | | |
| Т | 0.62 | 1.28 | 2.27 | 3.51 | 4.45 | | | |
| E or "-": default | 0.54 | 1.00 | 2.01 | 3.10 | 4.01 | | | |
| U | 0.43 | 0.96 | 1.81 | 2.79 | 3.65 | | | |
| F | 0.34 | 0.88 | 1.64 | 2.54 | 3.32 | | | |

Table 1. Vdd = 1.8V Rise/Fall Times for Specific C_{LOAD}

Table 2. Vdd = 2.5V Rise/Fall Times for Specific C_{LOAD}

| | Rise/Fall Time Typ (ns) | | | | | | | | |
|------------------------------------|-------------------------|-------|-------|-------|-------|--|--|--|--|
| Drive Strength \ C _{LOAD} | 5 pF | 15 pF | 30 pF | 45 pF | 60 pF | | | | |
| L | 3.77 | 7.54 | 12.28 | 19.57 | 25.27 | | | | |
| А | 1.94 | 3.90 | 7.03 | 10.24 | 13.34 | | | | |
| R | 1.29 | 2.57 | 4.72 | 7.01 | 9.06 | | | | |
| В | 0.97 | 2.00 | 3.54 | 5.43 | 6.93 | | | | |
| Т | 0.55 | 1.12 | 2.08 | 3.22 | 4.08 | | | | |
| E or "-": default | 0.44 | 1.00 | 1.83 | 2.82 | 3.67 | | | | |
| U | 0.34 | 0.88 | 1.64 | 2.52 | 3.30 | | | | |
| F | 0.29 | 0.81 | 1.48 | 2.29 | 2.99 | | | | |

| Rise/Fall Time Typ (ns) | | | | | | | | |
|------------------------------------|------|-------|-------|-------|-------|--|--|--|
| Drive Strength \ C _{LOAD} | 5 pF | 15 pF | 30 pF | 45 pF | 60 pF | | | |
| L | 3.60 | 7.21 | 11.97 | 18.74 | 24.30 | | | |
| А | 1.84 | 3.71 | 6.72 | 9.86 | 12.68 | | | |
| R | 1.22 | 2.46 | 4.54 | 6.76 | 8.62 | | | |
| В | 0.89 | 1.92 | 3.39 | 5.20 | 6.64 | | | |
| T or "-": default | 0.51 | 1.00 | 1.97 | 3.07 | 3.90 | | | |
| E | 0.38 | 0.92 | 1.72 | 2.71 | 3.51 | | | |
| U | 0.30 | 0.83 | 1.55 | 2.40 | 3.13 | | | |
| F | 0.27 | 0.76 | 1.39 | 2.16 | 2.85 | | | |

Table 3. Vdd = 2.8V Rise/Fall Times for Specific CLOAD

| | Rise/Fall Time Typ (ns) | | | | | | | | |
|------------------------------------|-------------------------|-------|-------|-------|-------|--|--|--|--|
| Drive Strength \ C _{LOAD} | 5 pF | 15 pF | 30 pF | 45 pF | 60 pF | | | | |
| L | 3.39 | 6.88 | 11.63 | 17.56 | 23.59 | | | | |
| А | 1.74 | 3.50 | 6.38 | 8.98 | 12.19 | | | | |
| R | 1.16 | 2.33 | 4.29 | 6.04 | 8.34 | | | | |
| В | 0.81 | 1.82 | 3.22 | 4.52 | 6.33 | | | | |
| T or "-": default | 0.46 | 1.00 | 1.86 | 2.60 | 3.84 | | | | |
| E | 0.33 | 0.87 | 1.64 | 2.30 | 3.35 | | | | |
| U | 0.28 | 0.79 | 1.46 | 2.05 | 2.93 | | | | |
| F | 0.25 | 0.72 | 1.31 | 1.83 | 2.61 | | | | |

Table 5. Vdd = 3.3V Rise/Fall Times for Specific C_{LOAD}

Table 4. Vdd = 3.0V Rise/Fall Times for Specific C_{LOAD}



The Smart Timing

Instant Samples with Time Machine and **Field Programmable Oscillators**

SiTime supports a field programmable version of the SiT1602 low power oscillator for fast prototyping and real time customization of features. The field programmable devices (FP devices) are available for all five standard SiT1602 package sizes and can be configured to one's exact specification using the Time Machine II, an USB powered MEMS oscillator programmer.

Customizable Features of the SiT1602 FP Devices Include

- 51 standard frequencies between 3.75 MHz and 77.76MHz (Refer to the frequency list page 10)
- Three frequency stability options, ±20 PPM, ±25 PPM, ±50 PPM
- Two operating temperatures, -20 to 70°C or -40 to 85°C
- Five supply voltage options, 1.8V, 2.5V, 2.8V, 3.0V, 3.3V and 2.25 to 3.65V continuous

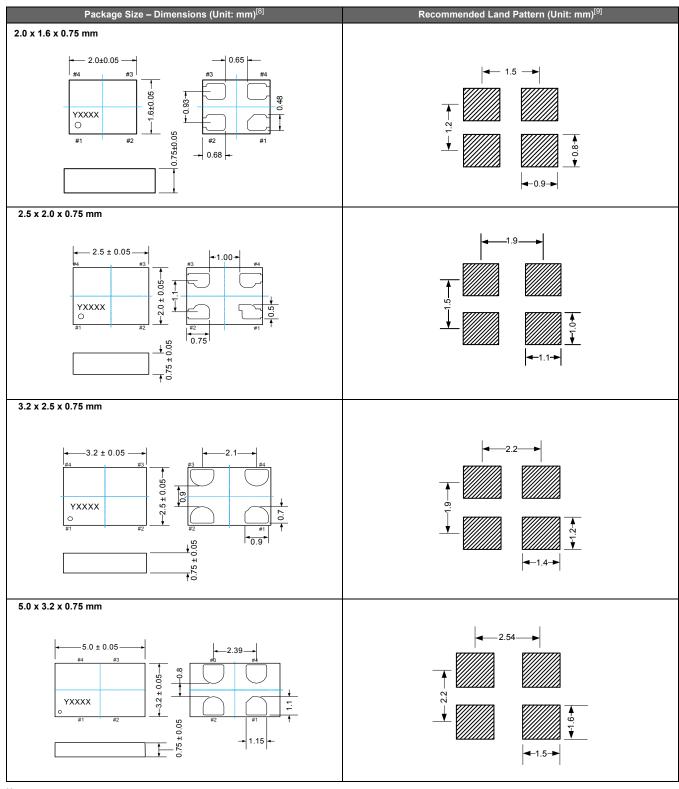
· Output drive strength

For more information regarding SiTime's field programmable solutions, visit http://www.sitime.com/time-machine and http://www.sitime.com/fp-devices.

SiT1602 is typically factory-programmed per customer ordering codes for volume delivery.



Dimensions and Patterns



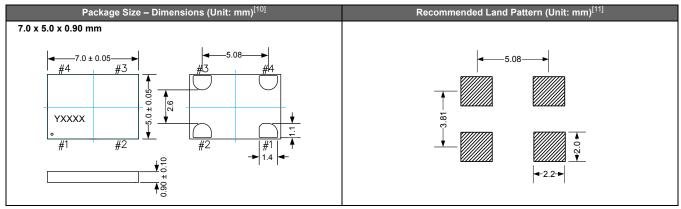
Notes:

Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
 A capacitor of value 0.1 μF between Vdd and GND is required.

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Dimensions and Patterns



Notes:

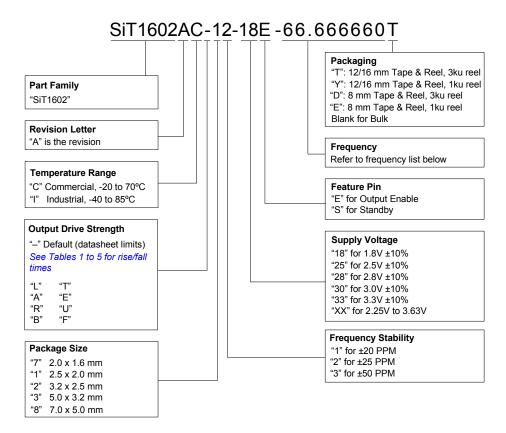
10. Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.

11. A capacitor of value 0.1 μ F between Vdd and GND is required.



Ordering Information

The Part No. Guide is for reference only. To customize and build an exact part number, use the SiTime Part Number Generator.



Supported Frequencies^[12]

| 3.57 MHz | 4 MHz | 4.096 MHz | 6 MHz | 7.3728 MHz | 8.192 MHz | 10 MHz | 12 MHz | 14 MHz |
|--------------|---------------|------------|------------|------------|-----------|---------------|-------------|--------------|
| 18.432 MHz | 19.2 MHz | 20 MHz | 24 MHz | 24.576 MHz | 25 MHz | 25.000625 MHz | 26 MHz | 27 MHz |
| 28.6363 MHz | 30 MHz | 31.25 MHz | 32.768 MHz | 33 MHz | 33.3 MHz | 33.33 MHz | 33.333 MHz | 33.3333 MHz |
| 33.33333 MHz | 37.5 MHz | 38 MHz | 38.4 MHz | 40 MHz | 40.5 MHz | 48 MHz | 50 MHz | 54 MHz |
| 60 MHz | 62.5 MHz | 65 MHz | 66 MHz | 66.6 MHz | 66.66 MHz | 66.666 MHz | 66.6666 MHz | 66.66666 MHz |
| 72 MHz | 74.175824 MHz | 74.176 MHz | 74.25 MHz | 75 MHz | 77.76 MHz | | | |

Note:

12. Contact SiTime for frequencies that are not listed in the above table.

Ordering Codes for Supported Tape & Reel Packing Method^[13]

| Device Size | 8 mm T&R (3ku) | 8 mm T&R (1ku) | 12 mm T&R (3ku) | 12 mm T&R (1ku) | 16 mm T&R (3ku) | 16 mm T&R (1ku) |
|--------------|----------------|----------------|-----------------|-----------------|-----------------|-----------------|
| 2.0 x 1.6 mm | D | E | - | - | - | - |
| 2.5 x 2.0 mm | D | E | - | - | - | - |
| 3.2 x 2.5 mm | D | E | - | - | - | - |
| 5.0 x 3.2 mm | - | - | Т | Y | - | - |
| 7.0 x 5.0 mm | - | - | - | - | Т | Y |

Note:

13. For "--", contact SiTime for availability.



Additional Information

| Document | Description | Download Link | | |
|-----------------------------------|---|--|--|--|
| Time Machine II | MEMS oscillator programmer | http://www.sitime.com/support/time-machine-oscillator-programmer | | |
| Field Programmable Oscillators | Devices that can be programmable in the field by Time Machine II | http://www.sitime.com/products/field-programmable-oscillators | | |
| Manufacturing Notes | Tape & Reel dimension, reflow profile and other manufacturing related info | http://www.sitime.com/component/docman/doc_download/85-manu facturing-notes-for-sitime-oscillators | | |
| Qualification Reports | RoHS report, reliability reports, composition reports | http://www.sitime.com/support/quality-and-reliability | | |
| Performance Reports | Additional performance data such as phase noise, current consumption and jitter for selected frequencies | http://www.sitime.com/support/performance-measurement-report | | |
| Termination Techniques | Termination design recommendations | http://www.sitime.com/support/application-notes | | |
| Layout Techniques | Layout recommendations | http://www.sitime.com/support/application-notes | | |

Revision History

| Version | Release Date | Change Summary |
|---------|--------------|--|
| 1.0 | 2/8/13 | Preliminary Information |
| 1.1 | 7/24/13 | Added programmable drive strength Added the Time Machine and FP device info Added performance plots Removed all footnotes related to softedge |
| 1.2 | 3/26/15 | Added 20 MHz to frequency selection |

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Supplemental Information

The Supplemental Information section is not part of the datasheet and is for informational purposes only.



Silicon MEMS Outperforms Quartz

990 Almanor Avenue, Sunnyvale, CA 94085

(408) 328-4400



Best Reliability

Silicon is inherently more reliable than quartz. Unlike quartz suppliers, SiTime has in-house MEMS and analog CMOS expertise, which allows SiTime to develop the most reliable products. Figure 1 shows a comparison with quartz technology.

Why is SiTime Best in Class:

- SiTime's MEMS resonators are vacuum sealed using an advanced EpiSeal[™] process, which eliminates foreign particles and improves long term aging and reliability
- · World-class MEMS and CMOS design expertise

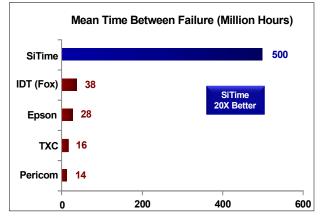


Figure 1. Reliability Comparison^[1]

Best Aging

Unlike quartz, MEMS oscillators have excellent long term aging performance which is why every new SiTime product specifies 10-year aging. A comparison is shown in Figure 2.

Why is SiTime Best in Class:

- SiTime's MEMS resonators are vacuum sealed using an advanced EpiSeal process, which eliminates foreign particles and improves long term aging and reliability
- Inherently better immunity of electrostatically driven MEMS resonator

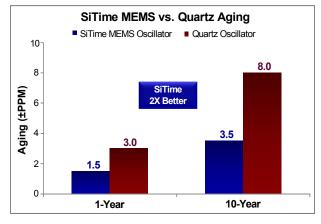


Figure 2. Aging Comparison^[2]

Best Electro Magnetic Susceptibility (EMS)

SiTime's oscillators in plastic packages are up to 54 times more immune to external electromagnetic fields than quartz oscillators as shown in Figure 3.

Why is SiTime Best in Class:

- Internal differential architecture for best common mode noise rejection
- Electrostatically driven MEMS resonator is more immune to EMS

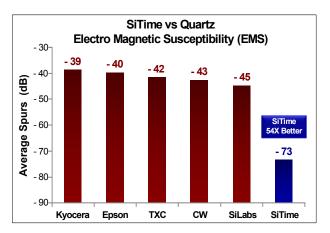


Figure 3. Electro Magnetic Susceptibility (EMS)^[3]

Best Power Supply Noise Rejection

SiTime's MEMS oscillators are more resilient against noise on the power supply. A comparison is shown in Figure 4.

Why is SiTime Best in Class:

- On-chip regulators and internal differential architecture for common mode noise rejection
- · Best analog CMOS design expertise

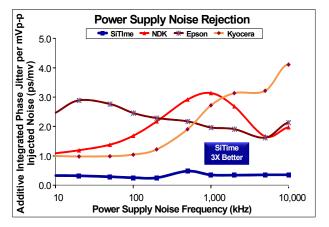


Figure 4. Power Supply Noise Rejection^[4]



Best Vibration Robustness

High-vibration environments are all around us. All electronics, from handheld devices to enterprise servers and storage systems are subject to vibration. Figure 5 shows a comparison of vibration robustness.

Why is SiTime Best in Class:

- The moving mass of SiTime's MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

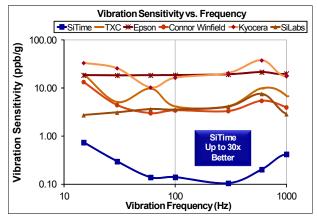


Figure 5. Vibration Robustness^[5]

Notes:

- 1. Data Source: Reliability documents of named companies.
- 2. Data source: SiTime and quartz oscillator devices datasheets.
- 3. Test conditions for Electro Magnetic Susceptibility (EMS):
 - According to IEC EN61000-4.3 (Electromagnetic compatibility standard)
 Eicle stage stage
 - Field strength: 3V/m
 - Radiated signal modulation: AM 1 kHz at 80% depth
 - Carrier frequency scan: 80 MHz 1 GHz in 1% steps
 - Antenna polarization: Vertical
 - · DUT position: Center aligned to antenna

Devices used in this test:

SiTime, SiT9120AC-1D2-33E156.250000 - MEMS based - 156.25 MHz Epson, EG-2102CA 156.2500M-PHPAL3 - SAW based - 156.25 MHz TXC, BB-156.250MBE-T - 3rd Overtone quartz based - 156.25 MHz Kyocera, KC7050T156.250P30E00 - SAW based - 156.25 MHz Connor Winfield (CW), P123-156.25M - 3rd overtone quartz based - 156.25 MHz SiLabs, Si590AB-BDG - 3rd overtone quartz based - 156.25 MHz

4. 50 mV pk-pk Sinusoidal voltage.

Devices used in this test:

SiTime, SiT8208AI-33-33E-25.000000, MEMS based - 25 MHz NDK, NZ2523SB-25.6M - quartz based - 25.6 MHz Kyocera, KC2016B25M0C1GE00 - quartz based - 25 MHz

- Epson, SG-310SCF-25M0-MB3 quartz based 25 MHz 5. Devices used in this test: same as EMS test stated in Note 3.
- 5. Devices used in this test: same as EMS test stated in
- Test conditions for shock test:
 MIL-STD-883F Method 2002
 - Condition A: half sine wave shock pulse, 500-g, 1ms
 - Continuous frequency measurement in 100 µs gate time for 10 seconds
 - Devices used in this test: same as EMS test stated in Note 3

7. Additional data, including setup and detailed results, is available upon request to qualified customers. Please contact productsupport@sitime.com.

Best Shock Robustness

SiTime's oscillators can withstand at least 50,000 g shock. They all maintain their electrical performance in operation during shock events. A comparison with quartz devices is shown in Figure 6.

Why is SiTime Best in Class:

- The moving mass of SiTime's MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

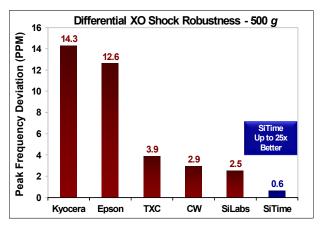


Figure 6. Shock Robustness^[6]

Document Feedback Form



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| If "Other," please spec | cify: | | | | | | | |
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